

1SS400G High Speed SWITCHING Diodes**FEATURES**

- Small surface mounting type
- High Speed
- High reliability with high surge current handling capability

SOD-723**Maximum Ratings and Electrical Characteristics, Single Diode @T_A=25°C**

Parameter	Symbol	Limits	Unit
Peak reverse voltage	V_{RM}	90	V
DC reverse voltage	V_R	80	V
Peak forward current	I_{FM}	225	mA
Mean rectifying current	I_O	100	mA
Surge current (1s)	I_{surge}	500	mA
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	-55~+125	°C

Electrical Ratings @T_A=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_F			1.2	V	$I_F=100mA$
Reverse current	I_R			0.1	μA	$V_R=80V$
Capacitance between terminals	C_T			3.0	pF	$V_R=0.5V, f=1MHz$
Reverse recovery time	t_{rr}			4	ns	$V_R=6V, I_F=10mA, R_L=100\Omega$

●Electrical characteristic curves (Ta = 25°C)

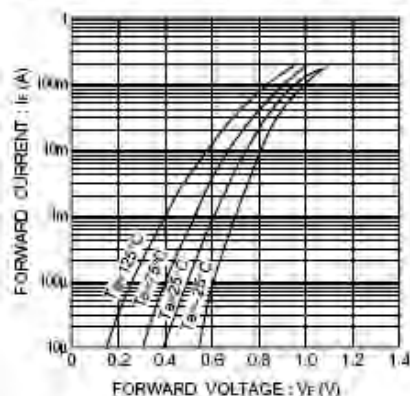


Fig.1 Forward characteristics

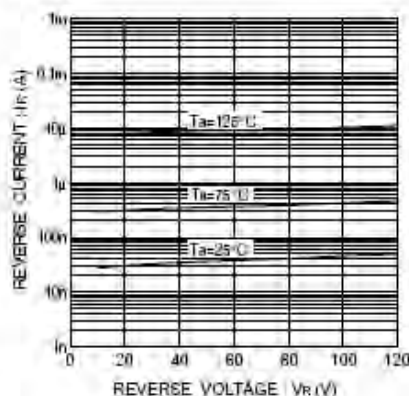


Fig.2 Reverse characteristics

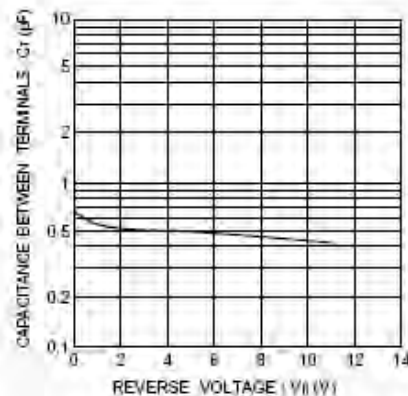


Fig.3 Capacitance between terminals

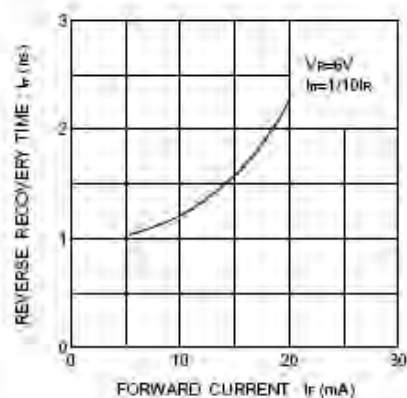


Fig.4 Reverse recovery time characteristics

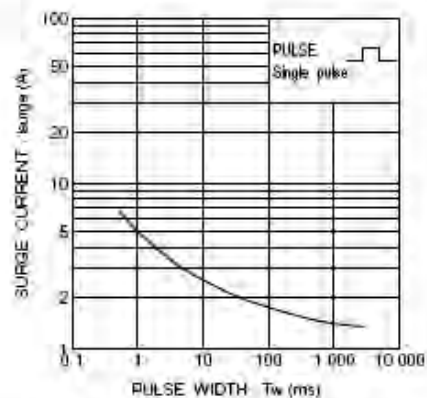


Fig.5 Surge current characteristics

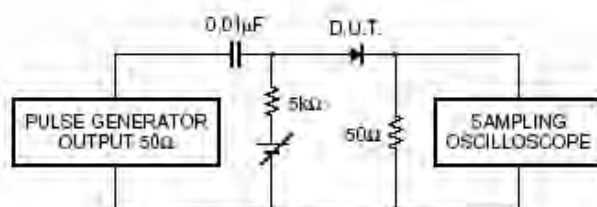


Fig.6 Reverse recovery time (tr) measurement circuit